NB3N5573

3.3V, Crystal - To- HCSL Clock Generator

ON Semiconductor®

http://onsemi.com

Description

The NB3N5573 is a high precision, low phase noise clock generator that supports PCI Express and Ethernet requirements. The device takes a 25 MHz fundamental mode parallel resonant crystal and generates differential HCSL output at 25 MHz, 100 MHz, 125 MHz or 200 MHz clock frequencies.

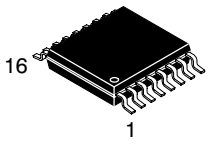
This device is housed in 5.0 mm x 4.4 mm narrow body TSSOP 16 pin package.

Features

- Uses 25 MHz Fundamental Mode Parallel Resonant Crystal
- External Loop Filter is Not Required
- HCSL Differential Output
- Phase Noise:

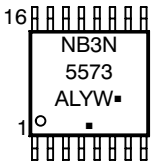
Offset	Noise Power
100 Hz	-103 dBc/Hz
1 kHz	-1 18 dBc/Hz
10 kHz	-122 dBc/Hz
100 kHz	-130 dBc/Hz
1 MHz	-132 dBc/Hz
10 MHz	-149 dBc/Hz

- Typical Period Jitter RMS of 1.5 ps
- Operating Range 3.3 V ±10%
- Industrial Temperature Range -40°C to +85°C
- These are Pb-Free Devices



TSSOP-16
DT SUFFIX
CASE 948F

MARKING DIAGRAM



A	= Assembly Location
L	= Wafer Lot
Y	= Year
W	= Work Week
▪	= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

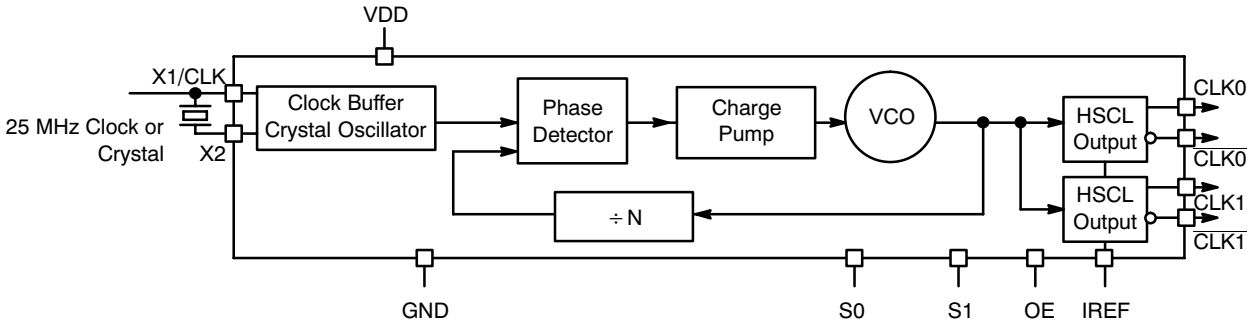


Figure 1. NB3N5573 Simplified Logic Diagram

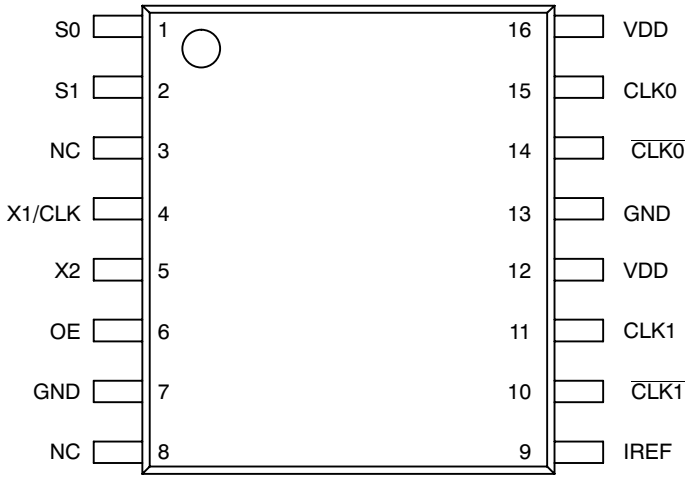


Figure 2. Pin Configuration (Top View)

Table 1. PIN DESCRIPTION

Pin	Symbol	I/O	Description
1	S0	Input	LVTTL/LVCMOS frequency select input 0. Internal pullup resistor to V_{DD}. See output select table 2 for details.
2	S1	Input	LVTTL/LVCMOS frequency select input 1. Internal pullup resistor to V_{DD}. See output select Table 2 for details.
12, 16	V_{DD}	Power Supply	Positive supply voltage pins are connected to +3.3 V supply voltage.
4	X1/CLK	Input	Crystal or Clock input. Connect to 25 MHz crystal source or single-ended clock.
5	X2	Input	Crystal input. Connect to a 25 MHz crystal or leave unconnected for clock input.
6	OE	Input	Output enable tri-states output when connected to GND. Internal pullup resistor to V_{DD}.
7, 13	GND	Power Supply	Ground 0 V. These pins provide GND return path for the devices.
9	I_{REF}	Output	Output current reference pin. Precision resistor (typ. 475 Ω) is connected to set the output current.
11	CLK1	HCSL Output	Noninverted clock output.
10	$\overline{CLK1}$	HCSL Output	Inverted clock output.
15	CLK0	HCSL Output	Noninverted clock output.
14	$\overline{CLK0}$	HCSL Output	Inverted clock output.
3, 8	NC		Do not connect

Table 2. OUTPUT FREQUENCY SELECT TABLE

S1	S0	f_{CLKout} (MHz)
L	L	25
L	H	100
H	L	125
H	H	200

Recommended Crystal Parameters

Crystal	Fundamental AT-Cut
Frequency	25 MHz
Load Capacitance	16-20 pF
Shunt Capacitance, C0	7 pF Max
Equivalent Series Resistance	35 Ω Max
Initial Accuracy at 25 °C	±20 ppm
Temperature Stability	±30 ppm
Aging	±20 ppm
C0/C1 Ration	250 Max

Table 3. ATTRIBUTES

Characteristic		Value
ESD Protection	Human Body Model	> 2 kV
Moisture Sensitivity, Indefinite Time Out of Dray Pack (Note 1)		Level 1
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
Transistor Count		7623
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test		

1. For additional information, see Application Note AND8003/D.

Table 4. MAXIMUM RATINGS (Note 2)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V_{DD}	Positive Power Supply	GND = 0 V		4.6	V
V_I	Input Voltage (V_{IN})	GND = 0 V	GND ≤ V_I ≤ V_{DD}	-0.5 V to V_{DD}+0.5 V	V
T_A	Operating Temperature Range			-40 to +85	°C
T_{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	TSSOP−16 TSSOP−16	138 108	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	(Note 3)	TSSOP-16	33 to 36	°C/W
T_{sol}	Wave Solder			265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

2. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and not valid simultaneously. If stress limits are exceeded device functional operation is not implied, damage may occur and reliability may be affected.
3. JEDEC standard multilayer board - 2S2P (2 signal, 2 power).

Table 5. DC CHARACTERISTICS (V_{DD} = 3.3 V ±10%, GND = 0 V, T_A = -40°C to +85°C, Note 4)

Symbol	Characteristic	Min	Typ	Max	Unit
VDD	Power Supply Voltage	2.97	3.3	3.63	V
I_{DD}	Power Supply Current		120	135	mA
I_{DDOE}	Power Supply Current when OE is Set Low			65	mA
V_{IH}	Input HIGH Voltage (X/CLK, S0, S1, and OE)	2000		V_{DD} + 300	mV
V_{IL}	Input LOW Voltage (X/CLK, S0, S1, and OE)	GND - 300		800	mV
V_{OH}	Output HIGH Voltage for HCSL Output (See Figure 4)	660	700	850	mV
V_{OL}	Output LOW Voltage for HCSL Output (See Figure 4)	-150	0	150	mV
V_{cross}	Crossing Voltage Magnitude (Absolute) for HCSL Output	250		550	mV
ΔV_{cross}	Change in Magnitude of V_{cross} for HCSL Output			150	mV

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

4. Measurement taken with outputs terminated with R_S = 33.2 Ω, R_L = 49.9 Ω, with test load capacitance of 2 pF and current biasing resistor set at 475 Ω. See Figure 3.

Table 6. AC CHARACTERISTICS (V_{DD} = 3.3 V ±10%, GND = 0 V, T_A = -40°C to +85°C; Note 5)

Symbol	Characteristic	Min	Typ	Max	Unit
f_{CLKIN}	Clock/Crystal Input Frequency		25		MHz
f_{CLKOUT}	Output Clock Frequency	25		200	MHz
Ω_{NOISE}	Phase-Noise Performance f_{CLKout} = 200 MHz				dBc/Hz
	@ 100 Hz offset from carrier		-103		
	@ 1 kHz offset from carrier		-1 18		
	@ 10 kHz offset from carrier		-122		
	@ 100 kHz offset from carrier		-130		
	@ 1 MHz offset from carrier		-132		
	@ 10 MHz offset from carrier		-149		
T_{jitter}	Period Jitter Peak-to-Peak (Note 6) f_{CLKout} = 200 MHz		10	20	ps
	Period Jitter RMS (Note 6) f_{CLKout} = 200 MHz		1.5	3	
	Cycle-Cycle RMS Jiter (Note 7) f_{CLKout} = 200 MHz		2	5	
	Cycle-to-Cycle Peak to Peak Jitter (Note 7) f_{CLKout} = 200 MHz		20	35	ps
OE	Output Enable/Disable Time			1	μs
t_{DUTY_CYCLE}	Output Clock Duty Cycle (Measured at cross point)	45	50	55	%
t_R	Output Risetime (Measured from 175 mV to 525 mV, Figure 4)	175	340	700	ps
t_F	Output Falltime (Measured from 525 mV to 175 mV, Figure 4)	175	340	700	ps
Δt_R	Output Risetime Variation (Single-Ended)			125	ps
Δt_F	Output Falltime Variation (Single-Ended)			125	ps
Stabilization Time	Stabilization Time From Powerup VDD = 3.3 V		3.0		ms

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

5. Measurement taken from differential output on single-ended channel terminated with R_S = 33.2 Ω, R_L = 49.9 Ω, with test load capacitance of 2 pF and current biasing resistor set at 475 Ω. See Figure 3.
6. Sampled with 10000 cycles.
7. Sampled with 1000 cycles.

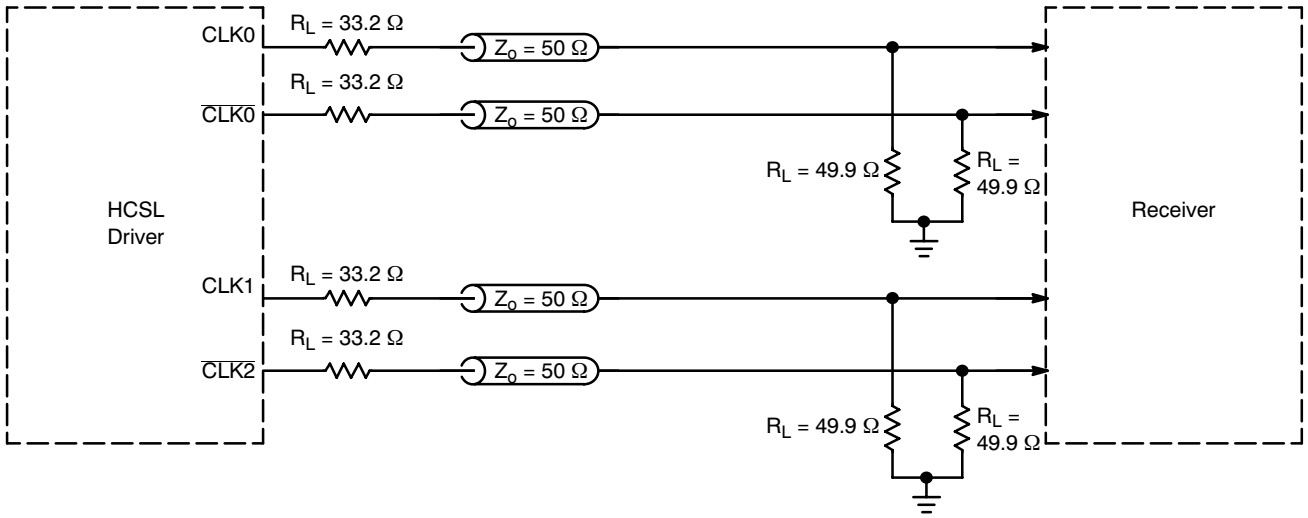


Figure 3. Typical Termination for Output Driver and Device Evaluation

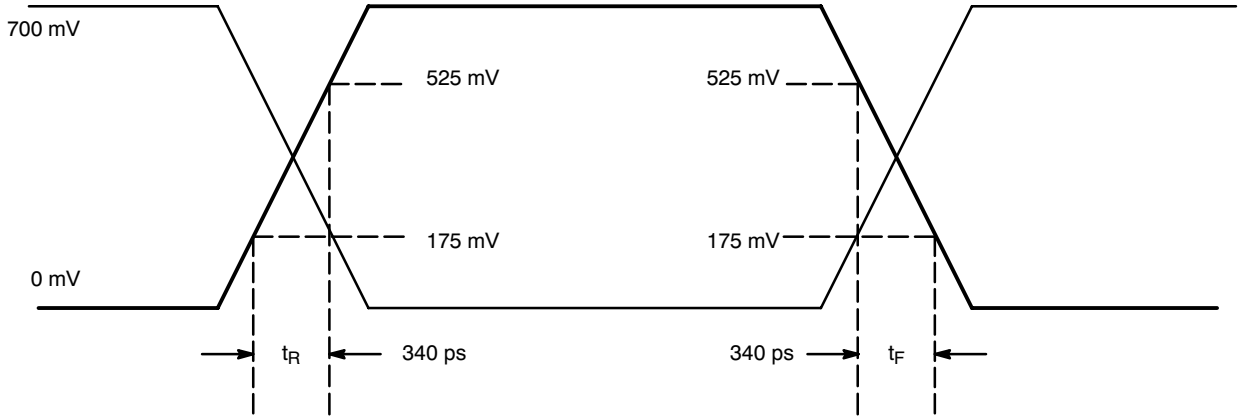


Figure 4. HCSL Output Parameter Characteristics

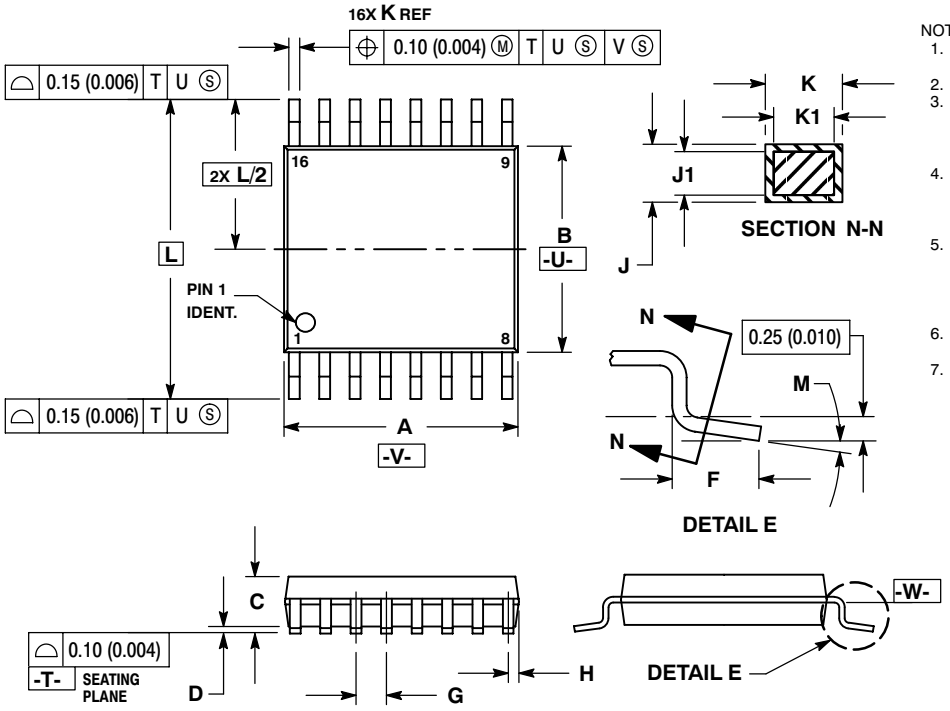
ORDERING INFORMATION

Device	Package	Shipping†
NB3N5573DTG	TSSOP-16 (Pb-Free)	96 Units / Rail
NB3N5573DTR2G	TSSOP-16 (Pb-Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

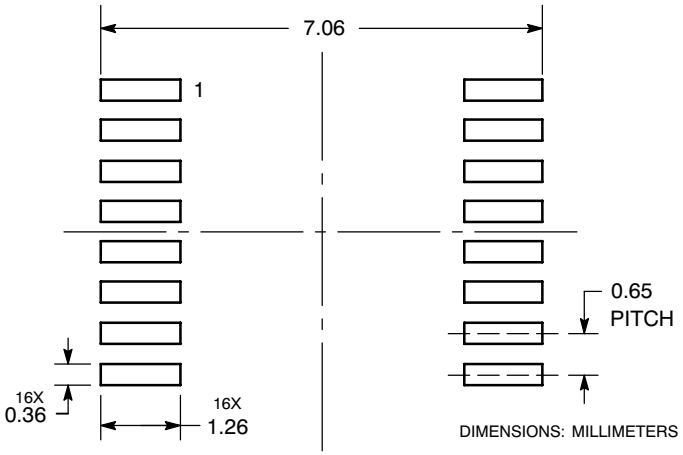
TSSOP-16
CASE 948F-01
ISSUE B



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0 °	8 °	0 °	8 °

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
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Email: orderlit@onsemi.com

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